Nanosized Vanadium Diboride: Synthesis, Structure, and Properties

S. E. Kravchenko^a, A. G. Burlakova^a, I. A. Domashnev^a, A. A. Vinokurov^a, and S. P. Shilkin^a*

^a Institute of Problems of Chemical Physics, Russian Academy of Sciences, pr. Semenova 1, Chernogolovka, Moscow oblast, 142432 Russia *e-mail: ssp@icp.ac.ru

Received November 8, 2018; revised November 8, 2018; accepted November 22, 2018

Abstract—X-ray diffraction, scanning electron microscopic, and X-ray photoelectron spectroscopic examinations, as well as energy dispersive X-ray and elemental analyses revealed the formation of single-phase VB₂ with the average particle sizes of 20–35 nm from the reaction between vanadium(III) chloride and sodium borohydride at a molar ratio of 1 : 10 in the temperature range of 595–930°C in an argon atmosphere at a contact time of 14–28 h. The reaction between amorphous boron and vanadium powders at 800°C in an argon atmosphere at a contact time of 32 h in Na₂B₄O₇ and KCl ionic melts gave VB₂ with the average particle size of ~90 nm.

Keywords: nanoparticles, vanadium diboride, sodium borohydride, vanadium(III) chloride, ionic melt

DOI: 10.1134/S1070363219040017

Vanadium diboride VB_2 is a typical representative of Group V metal diborides. High melting point, as well as high hardness, strength, wear and impact resistance, chemical and corrosion inertness, and some other properties make VB_2 a promising material for applications such as high-temperature technology, vanadium boride air cells, and catalysts of liquid-phase oxidation of various organic compounds containing a double bond, e.g., of cyclooctene, with molecular oxygen [1–9].

Group IV–V metal borides attract today heightened interest from materials scientists due to promise they offer for the development of nanoscale materials whose physicochemical, mechanical, and other properties significantly differ from those of microcrystalline materials [10].

In this context, development of new efficient synthesis routes to nanoscale vanadium diboride is particularly important. Existing routes include direct synthesis from elements (sintering at high temperatures), borothermal reduction of various vanadium oxides and salts, carbothermal reduction of vanadium and boron oxides, mechanochemical synthesis, and plasma-chemical synthesis in a low-temperature nitrogen plasma [11–23].

Sintering provides is a facile route to high-speed synthesis of vanadium boride [11], but the resulting VB₂ appears as a molten sinter admixed with vanadium and boron oxides. A VB₂ powder with sufficiently large with particle sizes of <300 nm was can be produced by borothermal reduction of NH₄VO₃ at 900–1000°C under argon in the presence of a NaCl–KCl ionic melt or without it by reaction (1) [12].

 $6NH_4VO_3 + 22B \rightarrow 6VB_2 + 6NH_3 + 5B_2O_3 + 3H_2O$, (1)

$$V_2O_3 + 7B \rightarrow 2VB_2 + 3BO, \qquad (2)$$

$$V_2O_3 + 2C + B4C \rightarrow 2VB_2 + 3CO,$$
 (3)

$$VCl_3 + 2LiBH_4 + LiH \rightarrow VB_2 + 3LiCl + 4.5H_2.$$
(4)

Vanadium diboride powder can be synthesized by reducing vanadium oxide V_2O_3 with boron in a vacuum at a temperature of >1500°C by reaction (2) [13] or from boron carbide at 1500°C in an argon atmosphere by reaction (3) [14]. Synthesis of vanadium diboride nanopowder by mechanochemical route in a high-energy ball mill by reaction (4) [15] gave a VB₂ powder with particle sizes of 15–60 nm after removal of lithium chloride.

Vanadium borides V_3B_2 , VB, V_5B_6 , V_3B_4 , V_2B_3 , and VB₂ were prepared by the method of self-propagating high-temperature synthesis from vanadium and

T, ℃	Ionic melt	Time, h	Chemical composition of the synthesis products	Phase composition of the synthesis products	Lattice constants, nm		$S_{\rm sp},{\rm m}^2/{ m g}$
					а	С	
420	_	48	$V_{0.98}B_{3.8}Cl_{0.3}H_{2.7}O_{0.01}$	X-phase ^c	_	_	_
495	_	40	$V_{1.01}B_{3.9}Cl_{0.4}H_{2.8}O_{0.04}$	X-phase ^c	_	—	_
570	—	32	$V_{1.1}B_{2.9} \ Cl_{0.2}H_{1.8}O_{0.03}$	$VB_2^{d} + X$ -phase ^c	_	—	_
595	_	28	VB _{2.02} O _{0.03}	VB_2^{d}	_	—	73.9
645	_	24	VB _{2.03} O _{0.03}	VB_2^{d}	_	—	64.4
725	_	18	VB _{2.01} O _{0.01}	VB ₂	0.3006	0.3046	53.2
850	_	16	VB _{2.03} O _{0.02}	VB ₂	0.3002	0.3038	39.2
930	_	14	VB _{2.03} O ₀₀₃	VB ₂	0.2997	0.3057	36.0
800	$Na_2B_4O_7$	32	VB _{2.01} O _{0.02}	VB ₂	0.2998	0.3045	12.5
	KCl	32	VB _{2.02} O _{0.02}	VB_2	0.3002	0. 3039	13.1

Table 1. Data for the reaction between VCl₃ and NaBH₄^a and between V and B powders^b in Na₂B₄O₇ and KCl ionic melts

^a Molar ratio 1 : 10, argon pressure 4 MPa. ^b Molar ratio 1 : 2, 800°C, argon pressure 4 MPa, 32 h. ^c Because of insufficient number of reflections the lattice constants of X-phase were not determined. ^d Because of insufficient number (3–4) and diffusivity of reflections the lattice constants of VB₂ were not determined under the conditions indicated.

amorphous boron powders and studied [16]. Nanosized vanadium boride with a particle size of ~36 nm was mechanochemically synthesized from a mixture of Mg, V_2O_5 , and B_2O_3 in a high-energy ball mill [17]. Reaction of VCl₄ with NaBH₄ and Mg at 650°C in a stainless steel autoclave reactor gave 50-100 nm VB₂ nanoparticles [18], and that of VCl_3 with NaBH₄ in a eutectic mixture of anhydrous lithium and sodium chlorides in a quartz reactor at 900°C, ~10 nm VB₂ nanoparticles [19]. Plasma synthesis of vanadium diboride with particle sizes of 46-60 nm at temperatures of 2000-2600 K in a low-temperature nitrogen plasma from a mixture of vanadium oxide and amorphous boron was studied [20]. Dispersed powders of various compounds, including VB₂ [21], were obtained using high-energy disintegration technique. Also, high-temperature synthesis of VB₂ via solidphase reaction of VCl₃ with MgB₂ was reported [22]. Transition metal chlorides reacted with boron and tin powders in a sealed ampule in a vacuum or under argon in the 700-900°C temperature range to give, depending on the reaction conditions, micro- and nanocrystalline transition metal borides, including VB₂ [23].

As alternatives to the above-described routes we consider herein the synthesis of VB_2 nanoparticles by the solid-phase reaction of VCl_3 with $NaBH_4$ and

"currentless" transport of vanadium to boron in ionic melts of different chemical compositions and structures.

Table 1 presents the data we obtained for the reaction of VCl₃ with NaBH₄ at a 1 : 10 molar ratio in the 420–930°C temperature range at an argon pressure of 4 MPa and a contact time of 14–48 h. It is seen that a single-phase nanoscale vanadium diboride was formed at \geq 595°C, i.e., at a temperature of intensive decomposition of sodium borohydride [24]. Chemical and X-ray energy dispersive analyses showed that the black powder obtained in the 595–930°C range had the composition VB_{2.01–2.03}O_{0.01–0.03}, without chlorine and hydrogen traces detected.

According to the XRD data, the resultant powder is vanadium diboride (hexagonal P6/mmm space group, AlB₂ type structure). No significant amounts of impurity phases were detected. The unit cell parameters (Table 1) of the VB₂ synthesized in the 595 –930°C temperature range are consistent with the reference data for VB₂: a = 0.2994-0.2998 nm, c = 0.3048-0.3056 nm [25].

Similarly to the synthesis of zirconium diboride [26], NaBH₄ first decomposes according to reaction (5), whereupon its decomposition products react with vanadium chloride by reaction (6). Diborane

Table 2. Average diameter of the VB₂ particle synthesized by reacting VCl₃ with NaBH₄ at a 1 : 10 molar ratio in the 595–930°C temperature range at the initial argon pressure of 4 MPa and contact time of 14–28 h, and average diameter of the particles synthesized by reacting powdered V and B in a 1 : 2 molar ratio at 800°C at an argon pressure of 4 MPa and contact time of 32 h in Na₂B₄O₇ and KCl ionic melts

<i>T</i> , °C	Ionic melt	Average particle diameter estimated from the electron microscopic data, nm	Coherent scattering region size D_{hkl} , nm	Average particle diameter estimated from the S_{sp} data, nm
595	_	~20	_	~ 16
645	-	~20	_	~18
725	_	~25	~10.0	~22
850	_	~32	~9.5	~30
930	_	~35	~10.0	~33
800	$Na_2B_4O_7$	~90	~80.0	~95
800	KCl	~90	~85.0	~90

formed by reaction (5) decomposes under the actual conditions [27], and its decomposition products also react with VCl₃. The overall scheme for the preparation of VB₂ is represented by reaction (7).

$$NaBH_4 \rightarrow NaH + 0.5 B_2H_6, \tag{5}$$

$$VCl_3 + 2 NaH + B_2H_6 \rightarrow VB_2 + 2NaCl + HCl + 3.5 H_2$$
, (6)

$$VCl_3 + 2NaBH_4 \rightarrow VB_2 + 2NaCl + HCl + 3.5 H_2.$$
(7)

The reaction of vanadium trichloride with a NaBH₄ excess at 570°C leads to a mixture of vanadium diboride and X-phase. Alongside broadened diffraction lines associated with VB₂, the diffraction patterns contain two weak diffuse lines which cannot be attributed to possible known phases in the system examined. At temperatures below 570°C the formation of vanadium diboride is not observed, and in the corresponding diffraction patterns there are two diffuse low-intensity reflections from X-phase of the total composition V_{0.98-1.01}B_{3.8-3.9}Cl_{0.3-0.4}H_{2.7-2.8}O_{0.01-0.04}.

Table 2 lists the average diameters of the VB₂ particles obtained by reacting VCl₃ with NaBH₄ at different temperatures. According to the scanning electron microscopy data, the vanadium diboride particles synthesized in the 595–930°C temperature range were near-spherical, rather than chip-shaped as is typical for compounds formed as a result of a chemical reaction. The VB₂ particle size estimated from the electron microscopy data is consistent with the equivalent diameter of the VB₂ particles, estimated from the measured specific surface area of the powder at the VB₂ density taken as 5.066 g/cm³ (Table 2). With

increasing synthesis temperature the VB₂ particles tend to grow in size. The VB₂ particles are predominantly aggregated. At the same time, the size of the coherent scattering regions D_{hkl} for the 595–930°C temperature range was estimated at ~10 nm. At the synthesis temperatures of 595 and 645°C vanadium diboride was poorly crystallized, and at ≥850°C the sample particles were noticeably agglomerated. Thus, the full range of the data presented suggests the optimal synthesis temperature of 725°C.

Table 1 also presents the data on the reaction between vanadium and boron powders taken in a 1 : 2 molar ratio at 800°C, argon pressure of 4 MPa, and contact time of 32 h in $Na_2B_4O_7$ and KCl ionic melts. This reaction followed the procedure previously developed for the synthesis of nanoscale TiB₂ [28].

Use of ionic melts, with their peculiar structure and properties, as a reaction medium is conducive for the production of metal borides in the form of dispersed powders. Chemical and X-ray energy-dispersive analyses showed that the vanadium diboride obtained under the conditions indicated has the composition $VB_{2.01-2.02}O_{0.02}$. According to the XRD data, the resultant powdered vanadium diboride (hexagonal space group P6/mmm, AlB₂ type structure) is a single phase; no significant amounts of impurity phases were detected. The lattice constants of the samples (Table 1) agree satisfactorily with the reference data for VB_2 . Analysis of nine reflections in the $2\theta = 10^{\circ} - 110^{\circ}$ measurement range revealed the coherent scattering region D_{hkl} sizes of ~80 and ~85 nm for the VB₂ particles obtained in the Na₂B₄O₇ and KCl ionic melts,

respectively. The amorphous component of VB_2 gave a halo (partly attributable to the substrate used for the sample deposition) with a maximum at 20°.

According to the scanning electron microscopy data, the powdered vanadium diboride synthesized in the both ionic melts consists of variously shaped particles some of which are close to spherical, with a diameter of ~90 nm (Table 2). The same diameters estimated from the measured specific surface areas under assumption of the spherical shape of the VB₂ particles ($S_{sp} = 12.5$ and $13.1m^2/g$) at their theoretical density of 5.066 g/cm³ were ~95 and ~90 nm for the Na₂B₄O₇ and KCl ionic melts, respectively. Hence, irrespective of the chemical composition and nature of the ionic melt, the average diameter of the powdered VB₂ particles is close to 90 nm.

Thus, in line with the ideas presented in [29], the observed transport of B to V in the Na₂B₄O₇ or KCl ionic melt can be explained by the formation of lowest-valence ions B^{2+} by reaction (8), followed by reaction (9) of these ions with vanadium to give VB₂.

$$B + 2B_{melt}^{3+} \leftrightarrow 3B_{melt}^{2+}, \qquad (8)$$

$$3B_{melt}^{2+} + V \rightarrow B_{melt}^{3+} + VB_2.$$
(9)

When heated in an argon atmosphere to 1000°C, the vanadium diboride samples synthesized by the both routes developed did not experience phase transitions accompanied by heat evolution or absorption or by a change in mass.

For more precisely determining the qualitative composition of the vanadium diboride surface, the X-ray photoelectron spectra of the samples were recorded. The XPS data show that VB₂ is the main component of the powders, with the V $2p_{3/2}$ electron binding energy being 512.6-512.8 eV, and the B1s electron binding energy, 188.6-188.9 eV, which is in agreement with the published data [30, 31]. Alongside the characteristic lines of vanadium diboride, weak lines corresponding to boron oxides or boric acid, vanadium pentoxide V₂O₅, and elemental boron were recorded (191.5-191.6, 516.8-517.0, 532.5-532.8, 529.7-530.3, and 186.9-187.1 eV). Therefore, an up to ~40 Å deep surface layer of the vanadium diboride powder contains an insignificant amount of vanadium oxides, boron oxide, or boric acid with elemental boron inclusions.

The position of the B1s peak at 191.5-191.6 eV in the XPS patterns corresponds to B_2O_3 or H_3BO_3 [31].

The IR-spectroscopic data support the first assumption, since the ATR-IR spectrum of the sample was almost identical to that of individual boric anhydride [32] and did not exhibit characteristic vibrations of H_3BO_3 (3200, 1450, and 1196 cm⁻¹) [33].

Thus, the two synthetic routes to nanoscale vanadium diboride we developed allow preparation of vanadium diboride of a near-stoichiometric composition with low oxygen content and average particle diameters of 20–35 and 85–90 nm.

EXPERIMENTAL

Sodium borohydride with >99.3% purity was obtained by crystallization of technical-grade reagent from 1 N NaOH solution and dried in a 1.33×10^{-2} Pa vacuum at 100°C. Commercial VCl₃ with a purity of 99.5%, high-purity argon [99.998%, TU (Technical Specifications) 2114-005-0024760-99], and reagent-grade potassium chloride were used. Grade B-99A amorphous boron (TU 1-92-154-90) with the particle size of 10–20 µm was preliminarily evacuated to a residual pressure of 1.3×10^{-1} Pa at 300°C. Anhydrous sodium tetraborate was obtained by dehydrating reagent-grade Na₂B₄O₇·5H₂O in a 1.3×10^{-1} Pa vacuum at 350°C.

Vanadium powder with the particle size of 10– 15 µm was obtained by activating commercial vanadium powder (99.8%) via heating at 900°C in a 1.3×10^{-1} Pa vacuum and then subjected to 5 hydrogenation–dehydrogenation cycles by the procedure described in [34]. The residual amount of hydrogen in the powder did not exceed 1.0×10^{-3} %, and that of oxygen, 3.0×10^{-3} %. The source of $\geq 99.999+$ % pure hydrogen was a self-contained laboratory-scale hydrogen generator in which hydride phases based on LaNi₅ and TiFe intermetallic compounds served as working materials and whose operation principle is described in detail in [35].

X-ray diffraction analysis was performed on an ADP-2 diffractometer (monochromatic CuK_a radiation). The error in determining the lattice constants of VB₂ did not exceed 0.0003 nm. Using the powder diffraction patterns, the coherent scattering region size D_{hkl} was calculated by the Scherrer formula (10) for the direction perpendicular to the *hkl* plane.

$$D_{hkl} = k\lambda/\beta_{hkl} \cos \theta_{hkl}.$$
 (10)

Here, k is the anisotropy coefficient taken to be 0.9, λ , X-ray radiation wavelength [λ (Cu K_{α}) 1.54178 Å], θ ,

diffraction angle, and β , full width at half maximum of the diffraction peak (in rad).

The attenuated total reflection infrared (ATR-IR) spectra in the range from 500 to 4000 cm⁻¹ were measured using PerkinElmer Spectrum 100 and Vertex 70V Fourier transform spectrometers equipped with attachments for recording the reflection spectra. Thermal studies were performed using a Netzsch STA 409 PC Luxx simultaneous thermal analyzer coupled to a QMS 403 C Aëolos quadrupole mass spectrometer, with a linear heating rate of 10°C/min in an argon stream over the temperature range from 20 to 1000°C. Electron-microscopic studies and energydispersive X-ray analysis (EDX) were performed on a complex consisting of a Zeiss Supra 25 field emission scanning electron microscope and an INCAx-sight X-ray energy-dispersive spectrometer. Electron microscopic images were obtained at low accelerating voltages of electron beam (~4 kV), at which the contribution to the recorded signal from the substrate is minimal or totally lacking. The EDX analysis was carried out at an accelerating voltage of ~8 kV. X-ray photoelectron spectra were recorded on a PHOIBOS 150 MCD electron spectrometer for chemical analysis. A Quadrasorb SI analyzer was used to measure the specific surface area. The boron, vanadium, chlorine, and oxygen contents were determined by standard analytical procedures, as well as by the energydispersive X-ray analysis technique. The hydrogen content was determined on a Vario EL cube Elementar CHNS/O elemental analyzer. The pressure in the system was measured using standard pressure gauges of accuracy class 0.4.

EXPERIMENTAL

a. A quartz ampule with weighed portions of vanadium trichloride and sodium borohydride taken in a 1 : 10 molar ratio was placed into a stainless steel autoclave in an atmosphere of ultrapure argon. Next, the autoclave reactor was evacuated at room temperature for 5 min at 1.33×10^{-2} Pa, filled with argon at a pressure of 4 MPa, and heated at the specified temperature for 14–48 h. The pressure in the reactor after the reaction reached 10 MPa due to hydrogen evolution. The reactor was evacuated and filled with argon. After opening the reactor in an argon atmosphere the reaction mass was sequentially treated with distilled water cooled to 3°C, acetone, and

ethanol and then evacuated for 5–6 h at 40°C to a residual pressure of 1.33×10^{-1} Pa. The resultant powder was again placed into the reactor, treated with hydrogen under flow conditions at a pressure of 5 MPa at 100°C, then evacuated at room temperature to a residual pressure of 1.33×10^{-1} Pa, and unloaded from the reactor in an argon atmosphere.

b. Powdered V and B taken in a 1 : 2 ratio (0.71 g V, 0.3 g B) were stirred with 0.7 g of sodium tetraborate or potassium chloride for 8 h in a vibratory mill (drum capacity 50 cm^3 , vanadium balls, ball load 1 : 1, vibration amplitude 10 mm, vibration frequency 28 Hz) in an argon atmosphere at room temperature until the mixture was completely homogenized. A weighed portion of the resultant mixture in a corundum crucible was placed into a stainless steel autoclave reactor. The reactor was evacuated to a residual pressure of 1.33×10^{-1} Pa, filled with argon at a pressure of 4 MPa, and heated for the specified time at 800°C. Next, the reactor was cooled down to ambient, and the reaction mass was unloaded. The sinter was crushed and sequentially treated with distilled water cooled to 3°C, ethanol, and acetone, and then evacuated to a residual pressure of 1.33×10^{-1} Pa. The resultant powder was again placed into the reactor, treated with hydrogen under flow conditions at a pressure of 5 MPa and temperature of 100°C, evacuated at room temperature to a residual pressure of 1.33×10^{-1} Pa, and unloaded from the reactor in an argon atmosphere.

FUNDING

This study was performed as part of the State task (state registration no. 0089-2019-0007) using the equipment of the Analytical Center for Collective Use of the Institute of Problems of Chemical Physics, Russian Academy of Sciences.

CONFLICT OF INTEREST

No conflict of interest was declared by the authors.

REFERENCES

- 1. Serebryakova, T.I., Neronov, V.A., and Peshev, P.D., *Vysokotemperaturnye boridy* (High-Temperature Borides), Chelyabinsk: Metallurgiya, 1991.
- Carenco, S., Portehault, D., Boissiere, C., Mezailles, N., and Sanchez, C., *Chem. Rev.*, 2013, vol. 113, no. 10, p. 7981. doi 10.1021/cr400020d

- 3. Gidikova, N., Mater. Sci. Eng., A, 2000, vol. 278, p. 181. doi 10.1016/S0921-5093(99)00596-1
- 4. Smirnyagina, N.N., Sizov, I.G., Semenov, A.P., and Vandanov, A.G., Fiz. Khim. Obrab. Mater., 2001, no. 2, p. 63.
- 5. Grigor'ev, O.N., Koval'chuk, V.V., Zaporozhets, O.N., Bega, N.D., Galanov, B.A., Prilutskii, E.V., Kotenko, V.A., Kutran', T.N., and Dordienko, N.A., Powder Metall. Met. Ceram., 2006, nos. 1-2, p. 47. doi 10.1007/s11106-006-0041-x
- 6. Trach, Yu. B., Schulze, B., Macota, O.I., and Bulgakova, L.V., J. Mol. Catal. A, 2006, vol. 258, p. 292. doi 10.1016/j.molcata.2006.05.069
- 7. Lefler, M., Stuart, J., Parkey, J., and Licht, S., J. Electrochem. Soc., 2016, vol. 163, no. 5, p. A781. doi 10.1149/2.0031606jes
- 8. Licht, S., Ghosh, S., Wang, B., Jiang, D., Hettige, C., Lau, J., and Asercion, J., ECS Trans., 2011, vol. 35, no. 33, p. 21. doi 10.1149/1.3655434
- 9. Prokhorov, A.M., Lyakishev, N.P., Burkhanov, G.S., and Dementev, V.A., Inorg. Mater., 1996, vol. 32, no. 11, p. 1195.
- 10. Andrievski, R.A. and Khatchoyan, A.V., Nanomaterials in *Extreme Environments*, Fundamentals and Applications, Berlin: Springer International, 2016. doi 10.1007/978-3-319-25331-2
- 11. Levashov, E.A., Rogachev, A.S., Kurbatkina, V.V., Maksimov, Yu.M., and Yukhvid, V.I., Perspektivnye materialy i tekhnologii samorasprostranyayushchegosya vysokotemperaturnogo sinteza (Promising Materials and Technologies of Self-Propagating High-Temperature Synthesis), Moscow: ID MISiS, 2011.
- 12. Wei, Y., Huang, Zh., Zhou, L., and Ran, S., Int. J. Mater. Res., 2015, vol. 9, p. 1. doi 10.3139/146.111286
- 13. Peshev, P., Leyarovska, L., and Bliznakov, G., J. Less-Common Metals, 1968, vol. 15, p. 259. doi 10.1016/0022-5088(68)90184-7
- 14. Krutskii, Yu.L., Maksimovskii, E.A., Krutskaya, T.M., Popov, M.V., Netskina, O.V., Nikulina, A.A., Cherkasova, N.Yu., and Kvashina, T.S., Russ. J. Appl. Chem., 2017, vol. 90, no. 9, p. 1379. doi 10.1134/ S1070427217090014
- 15. Kim, J.W., Shim, J.H., Ahn, J.P., Cho, Y.W., Kim, J.H., and Oh, K.H., Mater. Lett., 2008, vol. 62, p. 2461. doi 10.1016/j.matlet.2007.12.022
- 16. Yeh, C.L. and Wang, H.J., J. Alloys Compd., 2011, vol. 509, p. 3257. doi 10.1016/j.jallcom.2010.12.004
- 17. Hassanzadeh-Tabrizi, S.A., Davoodi, D., Beykzadeh, A.A., and Salahshour, S., Ceram. Int., 2016, vol. 42, p. 1812. doi 10.1016/j.ceramint.2015.09.144
- 18. Shi, L., Gu, Y., Chen, L., Yang, Z., Ma, J., and Qian, Y., Mater. Lett., 2004, vol. 58, p. 2890. doi 10.1016/

j.matlet.2004.05.013

- 19. Portehaut, D., Devis, S., Beaunier, P., Gervais, C., Giordano, C., Sanchez, C., and Antonietti, M., Angew. Chem., 2011, vol. 50, p. 3262. doi 10.1002/ anie.201006810
- 20. Nozdrin, I.V., Galevskii, G.V., Shiryaeva, L.S., and Terent'eva, M.A., Steel Transl., 2011, vol. 41, no. 10, p. 799. doi 10.3103/S0967091211100147
- 21. Avakumov, E.G., Mekhanicheskie metody aktivatsii khimicheskikh protsessov (Mechanical Methods of Activation of Chemical Processes), Moscow: Nauka, Novosibirsk, 1989.
- 22. Rao, L., Gillan, E.G., and Kaner, R.B., J. Mater. Res., 1995, vol. 10, no. 2, p. 353. doi 10.1557/ JMR.1995.0353
- 23. Jothi, P.R., Yubuta, K., and Fokwa, B.P.T., Adv. Mater., 2018, vol. 30, no. 14, p. 1704181. doi 10.1002/ adma.20170418
- 24. Dymova, T.N., Eliseeva, N.G., and Mikheeva, V.I., Zh. Neorg. Khim., 1967, vol. 12, no. 9, p. 2317.
- 25. Diagrammy sostoyania dvoinykh metallicheskikh sistem (Phase Diagrams of Binary Metal Systems), Lyakishev, N.P., Ed., Moscow: Mashinostroenie, 1996, vol. 1.
- 26. Chen, L., Gu, Y., Yang, Z., Shi, L., Ma, J., and Qian, Y., Scripta Mater., 2004, vol. 50, p. 959. doi 10.1016/ j.scriptamat.2004.01.01
- 27. Mikhailov, B.M., Khimiya borovodorodov (Chemistry of Boron Hydrides), Moscow: Nauka, 1967.
- 28. Volkova, L.S., Shulga, Y.M., and Shilkin, S.P., Russ. J. Gen. Chem., 2012, vol. 82, no. 5, p. 819. doi 10.1134/ S1070363212050027
- 29. Ilyushchenko, N.G., Anfinogenov, A.I., and Shurov, N.I., Vzaimodeistvie metallov v ionnykh rasplavakh (Interaction of Metals in Ionic Melts), Moscow: Nauka, 1991.
- 30. Aleshin, V.G., Kharlamov, A.N., and Chudinov, M.G., Izv. Akad. Nauk SSSR, Ser. Neorg. Mater., 1979, vol. 15, no. 4, p. 672.
- 31. Terlan, B., Levin, A.A., Börrnert, F., Simon, F., Oschatz, M., Schmidt, M., Cardoso-Gil, R., Lorenz, T., Baburin, I.A., Joswig, J.-O., and Eychmüller, A., Chem. Mater., 2015, vol. 27, no. 14, p. 5106. doi 10.1021/ acs.chemmater.5b01856
- 32. Sidorov, T.A. and Sobolev, N.N., Opt. Spektrosk., 1958, vol. 4, no. 1, p. 9.
- 33. Bethell, D.E. and Sheppard, N., Trans. Faraday Soc., 1955, vol. 51, p. 9. doi 10.1039/TF9555100009
- 34. Semenenko, K.N., Shilkin, S.P., Burnasheva, V.V., Volkova, L.S., Govorkova, L.V., and Mozgina, N.G., Zh. Obshch. Khim., 1984, vol. 54, no. 3, p. 491
- 35. Fokin, V.N., Fokina, E.E., and Shilkin, S.P., Zh. Obshch. Khim., 1996, vol. 66, no. 8, p. 1249.

646